

**Vishay Semiconductors** 

# High Speed Infrared Emitting Diodes, 890 nm, GaAlAs, DH



### DESCRIPTION

VSMF2890RG(G)X01 series are infrared, 890 nm emitting diodes in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

### **FEATURES**

- · Package type: surface mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8
- AEC-Q101 gualified
- Peak wavelength: λ<sub>p</sub> = 890 nm
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 12^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2000X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **APPLICATIONS**

- IrDA compatible data transmission
- 3D TV
- Miniature light barrier
- Photointerrupters
- · Optical switch
- · Shaft encoders
- IR emitter source for proximity applications

PRODUCT SUMMARY					
COMPONENT	l <sub>e</sub> (mW/sr)	φ <b>(deg)</b>	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)	
VSMF2890RGX01	40	± 12	890	30	
VSMF2890GX01	40	± 12	890	30	

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMF2890RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMF2890GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

• MOQ: minimum order quantity

\*\* Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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AUTOMOTIVE RoHS COMPLIANT GREEN (5-2008)



### Vishay Semiconductors High Speed Infrared Emitting Diodes, 890 nm, GaAlAs, DH

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	5	V
Forward current		IF	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А
Power dissipation		Pv	160	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	Acc. figure 9, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	250	K/W

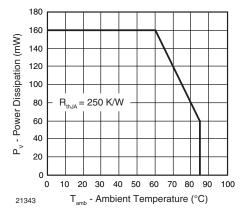
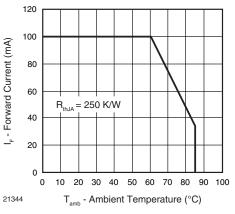


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature





BASIC CHARACTERSITICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	1.25	1.4	1.6	V
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	V <sub>F</sub>		2.3		V
Temperature coefficient of $V_{\rm F}$	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		- 1.8		mV/K
	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>		- 1.1		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0 mW/cm <sup>2</sup>	CJ		125		pF
Radiant intensity	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	l <sub>e</sub>	20	40	60	mW/sr
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs I <sub>e</sub>		350		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ <sub>e</sub>		40		mW
Temperature coefficient of $\phi_{\text{e}}$	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>		- 0.35		%/K
Angle of half intensity		φ		± 12		deg
Peak wavelength	I <sub>F</sub> = 30 mA	λ <sub>p</sub>	870	890	910	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ		40		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	TKλp		0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>		30		ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>		30		ns
Cut-off frequency	I <sub>DC</sub> = 70 mA, I <sub>AC</sub> = 30 mA pp	f <sub>c</sub>		12		MHz
Virtual source diameter		d		1.5		mm

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### BASIC CHARACTERSITICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

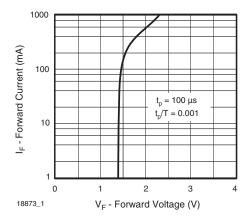


Fig. 3 - Forward Current vs. Forward Voltage

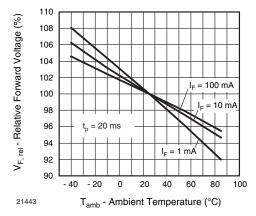


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

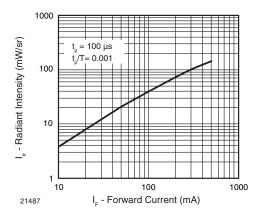


Fig. 5 - Radiant Intensity vs. Forward Current

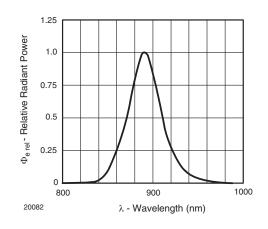


Fig. 6 - Relative Radiant Power vs. Wavelength

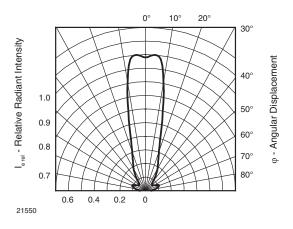


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

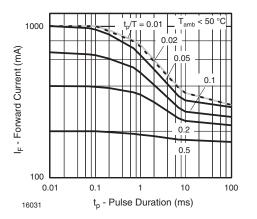


Fig. 8 - Pulse Forward Current vs. Pulse Duration

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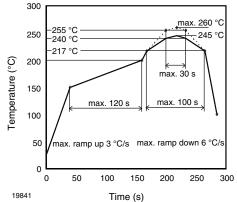
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### **SOLDER PROFILE**



## Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

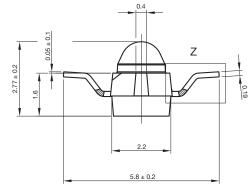
Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

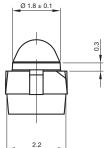
Moisture sensitivity level 2a, acc. to J-STD-020.

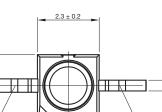
#### DRYING

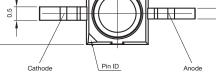
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

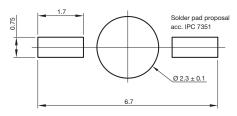
#### PACKAGE DIMENSIONS in millimeters: VSMF2890RGX01





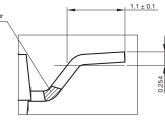






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 $2.3 \pm 0.2$ 

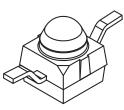


Z 20:1

exposed copp



Not indicated tolerances ± 0.1



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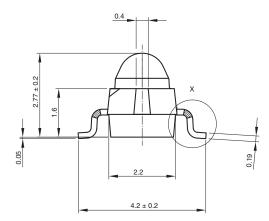
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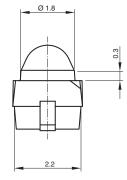
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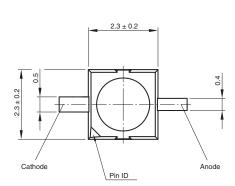


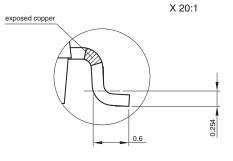
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### PACKAGE DIMENSIONS in millimeters: VSMF2890GX01



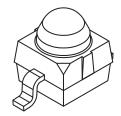


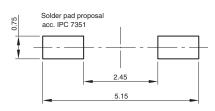






Not indicated tolerances  $\pm 0.1$ 





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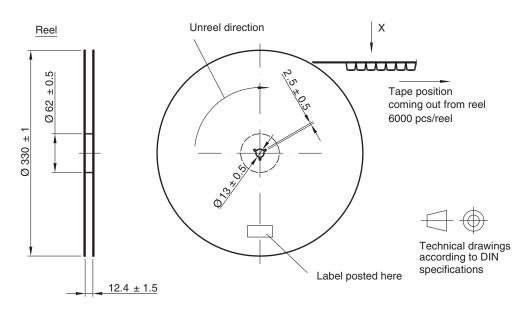
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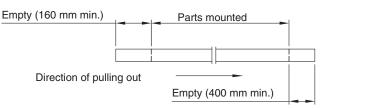
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### TAPING AND REEL DIMENSIONS in millimeters: VSMF2890RGX01



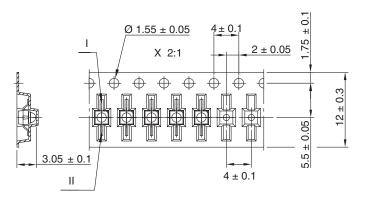
Leader and trailer tape:



Terminal position in tape

Devicce	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	O a the a dia	Anode
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode

Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10 21572

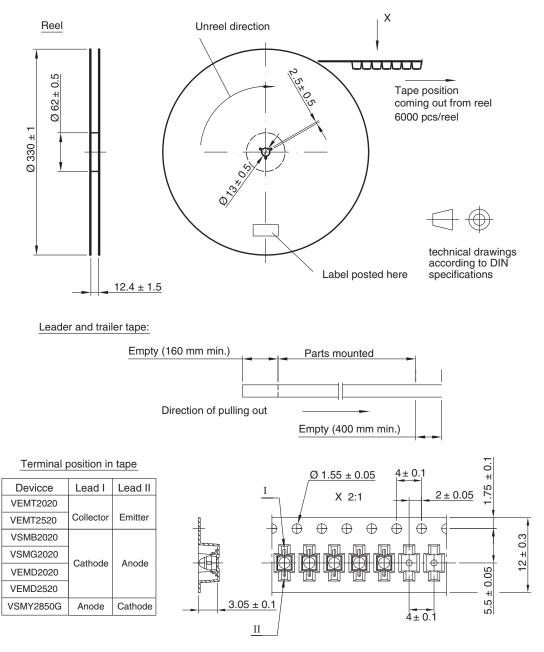


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### TAPING AND REEL DIMENSIONS in millimeters: VSMF2890GX01



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